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April 1st, 2010 Renesas Electronics Corporation

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MOS FIELD EFFECT TRANSISTOR μ PA2716AGR

SWITCHING P-CHANNEL POWER MOS FET

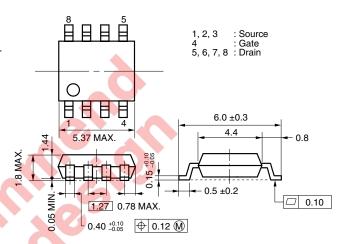
DESCRIPTION

The μ PA2716AGR is P-Channel MOS Field Effect Transistor designed for power management applications of notebook computers and Lithium-Ion battery protection circuit.

FEATURES

- · Low on-state resistance
 - $R_{DS(on)1}$ = 7.0 m Ω MAX. (VGs = -10 V, ID = -7.0 A) $R_{DS(on)2}$ = 11.3 m Ω MAX. (VGs = -4.5 V, ID = -7.0 A)
- Low input capacitance
 C_{iss} = 3000 pF TYP.
- · Built-in gate protection diode
- Small and surface mount package (Power SOP8)

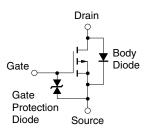
PACKAGE DRAWING (Unit: mm)



ABSOLUTE MAXIMUM RATINGS (TA = 25°C, All terminals are connected.)

Drain to Source Voltage (Vgs = 0 V)	Voss	-30	V
Gate to Source Voltage (V _{DS} = 0 V)		∓20	V
Drain Current (DC)	I _{D(DC)}	∓14	Α
Drain Current (pulse) Note1	ID(pulse)	∓140	Α
Total Power Dissipation Note2	P _{T1}	2	W
Total Power Dissipation Note3	P _{T2}	2	W
Channel Temperature	Tch	150	°C
Storage Temperature	Tstg	-55 to +150	°C
Single Avalanche Current Note4	las	-14	Α
Single Avalanche Energy Note4	Eas	19.6	mJ

EQUIVALENT CIRCUIT



- **Notes 1.** PW \leq 10 μ s, Duty Cycle \leq 1%
 - 2. Mounted on ceramic substrate of 1200 mm² x 2.2 mm
 - 3. Mounted on glass epoxy board of 25.4 mm x 25.4 mm x 0.8 mm, PW = 10 sec
 - **4.** Starting T_{ch} = 25°C, V_{DD} = -15 V, R_G = 25 Ω , L = 100 μ H, V_{GS} = -20 \rightarrow 0 V

Remark The diode connected between the gate and source of the transistor serves as a protector against ESD. When this device actually used, an additional protection circuit is externally required if a voltage exceeding the rated voltage may be applied to this device.

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ELECTRICAL CHARACTERISTICS (TA = 25°C, All terminals are connected.)

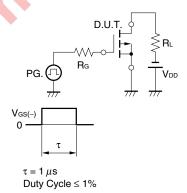
CHARACTERISTICS	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNIT
Zero Gate Voltage Drain Current	IDSS	V _{DS} = -30 V, V _{GS} = 0 V			-1	μA
Gate Leakage Current	Igss	V _{GS} = ∓20 V, V _{DS} = 0 V			∓10	μΑ
Gate to Source Cut-off Voltage	V _{GS(off)}	$V_{DS} = -10 \text{ V}, I_{D} = -1 \text{ mA}$	-1.0		-2.5	V
Forward Transfer Admittance Note	y _{fs}	V _{DS} = -10 V, I _D = -7.0 A	10			S
Drain to Source On-state Resistance Note	RDS(on)1	$V_{GS} = -10 \text{ V}, I_D = -7.0 \text{ A}$		5.5	7.0	mΩ
	RDS(on)2	$V_{GS} = -4.5 \text{ V}, I_D = -7.0 \text{ A}$		7.3	11.3	mΩ
	RDS(on)3	$V_{GS} = -4.0 \text{ V}, I_D = -7.0 \text{ A}$		8.3	13.5	mΩ
Input Capacitance	Ciss	V _{DS} = -10 V		3000		pF
Output Capacitance	Coss	V _{GS} = 0 V		960		pF
Reverse Transfer Capacitance	Crss	f = 1 MHz		500		pF
Turn-on Delay Time	t _{d(on)}	V _{DD} = -15 V, I _D = -7.0 A		14		ns
Rise Time	tr	V _{GS} = -10 V		19		ns
Turn-off Delay Time	t d(off)	R _G = 10 Ω		680		ns
Fall Time	tf			340		ns
Total Gate Charge	QG	V _{DD} = -24 V		95		nC
Gate to Source Charge	Qgs	V _{GS} = -10 V		11		nC
Gate to Drain Charge	Q _{GD}	I _D = -14 A		25		nC
Body Diode Forward Voltage Note	V _{F(S-D)}	I _F = 14 A, V _{GS} = 0 V		0.83		V
Reverse Recovery Time	trr	I _F = 14 A, V _{GS} = 0 V		380		ns
Reverse Recovery Charge	Qrr	di/dt = 50 A/μs		690		nC

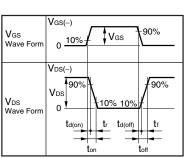
Note Pulsed

TEST CIRCUIT 1 AVALANCHE CAPABILITY

$R_{G} = 25 \Omega$ V_{DD} V_{DD}

TEST CIRCUIT 2 SWITCHING TIME





TEST CIRCUIT 3 GATE CHARGE

$$\begin{array}{c|c} D.U.T. \\ \hline \\ IG = -2 \text{ mA} \\ \hline \\ PG. \\ \hline \\ \end{array}$$

0

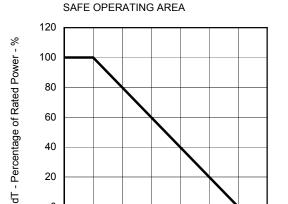
0

25

50

TYPICAL CHARACTERISTICS (TA = 25°C)

DERATING FACTOR OF FORWARD BIAS



T_A - Ambient Temperature - °C

100

125

150

175

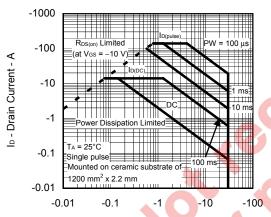
75

AMBIENT TEMPERATURE 2.8 Mounted on ceramic Pr - Total Power Dissipation - W 2.4 substrate of 1200 mm² x 2.2 mm 2 1.6 1.2 8.0 0.4 0 0 25 75 100 125 150 175

TOTAL POWER DISSIPATION vs.

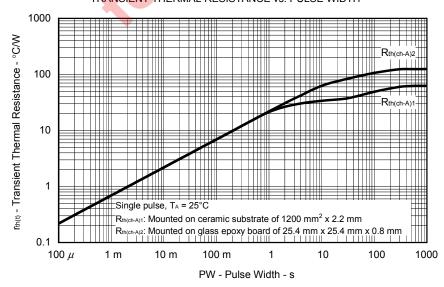
T_A - Ambient Temperature - °C

FORWARD BIAS SAFE OPERATING AREA

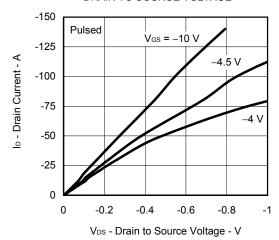


V_{DS} - Drain to Source Voltage - V

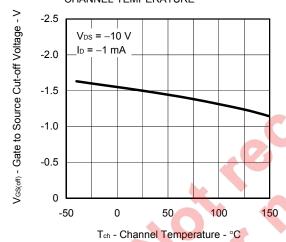
TRANSIENT THERMAL RESISTANCE vs. PULSE WIDTH



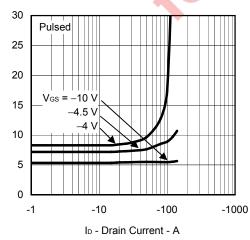
DRAIN CURRENT vs. DRAIN TO SOURCE VOLTAGE



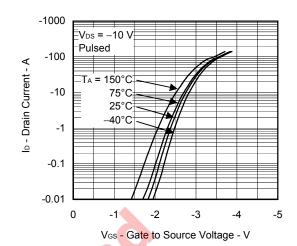
GATE TO SOURCE CUT-OFF VOLTAGE vs. CHANNEL TEMPERATURE



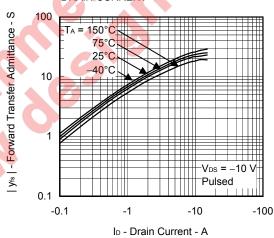
DRAIN TO SOURCE ON-STATE RESISTANCE vs. DRAIN CURRENT



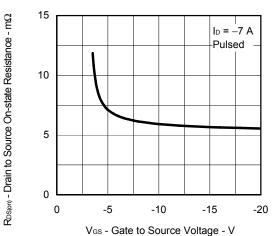
FORWARD TRANSFER CHARACTERISTICS



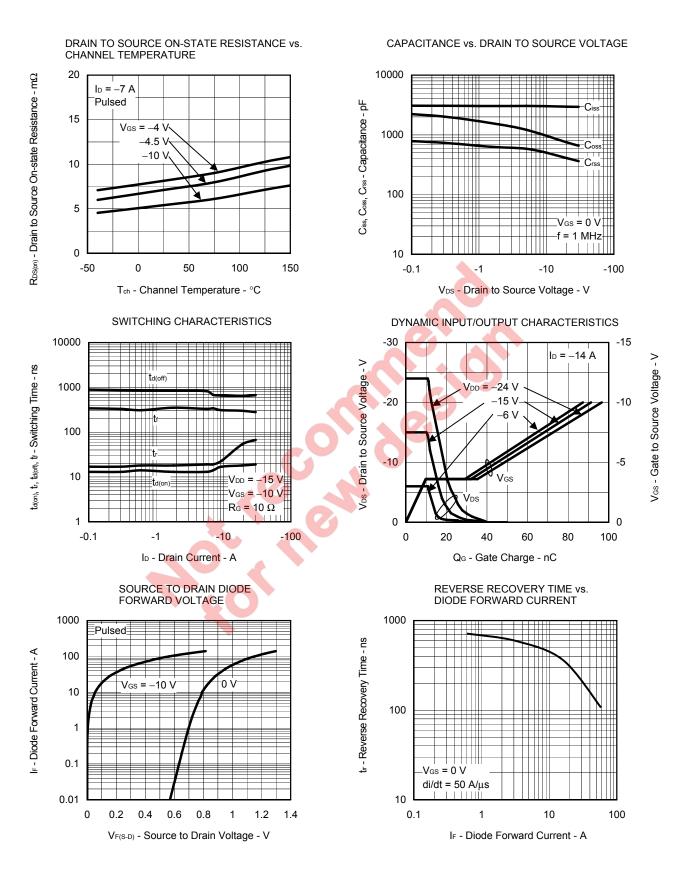
FORWARD TRANSFER ADMITTANCE vs. DRAIN CURRENT

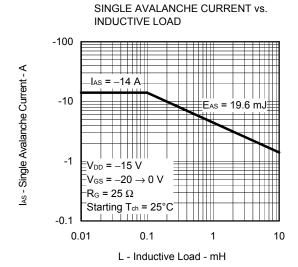


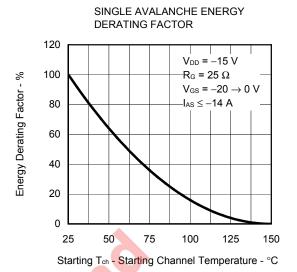
DRAIN TO SOURCE ON-STATE RESISTANCE vs. GATE TO SOURCE VOLTAGE



R_{DS(on)} - Drain to Source On-state Resistance - mΩ







ORDERING INFORMATION

PART NUMBER	LEAD PLATING	PACKING	PACKAGE
μPA2716AGR-E1-AT Note	Pure Sn (Tin)		Power SOP8
μPA2716AGR-E2-AT Note		Tape 2500 p/reel	0.08 g TYP.

Note Pb-free (This product does not contain Pb in external electrode and other parts.)

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